INTEGRATED CIRCUITS

DATA SHEET

74LVT863.3V Quad 2-input exclusive-OR gate

Product specification

1996 Sep 10

IC24 Data Handbook



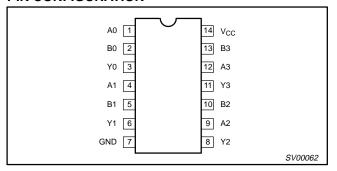


74LVT86

QUICK REFERENCE DATA

SYMBOL	PARAMETER	GND = 0V						
t _{PLH} t _{PHL}	Propagation delay An or Bn to Yn	$C_L = 50pF;$ $V_{CC} = 3.3V$	3.4 3.5	ns				
C _{IN}	Input capacitance	V _I = 0V or 3.0V	3	pF				
I _{CCL}	Total supply current	Outputs Low; V _{CC} = 3.6V	1	mA				

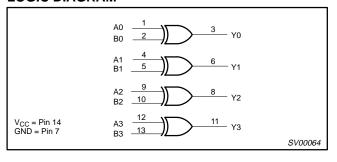
PIN CONFIGURATION



PIN DESCRIPTION

PIN NUMBER	TEVMBOLL NAME AND ELINOTI					
1, 2, 4, 5, 9, 10, 12, 13	A _n , B _n	Data inputs				
3, 6, 8, 11	Yn	Data outputs				
7	GND	Ground (0V)				
14	V _{CC}	Positive supply voltage				

LOGIC DIAGRAM



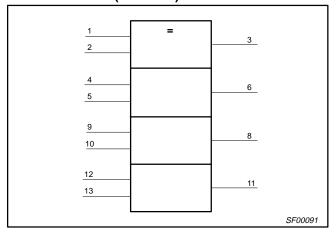
FUNCTION TABLE

INP	JTS	OUTPUT					
Dna	Dnb	Qn					
L	L	L					
L	Н	Н					
Н	L	Н					
Н	Н	L					

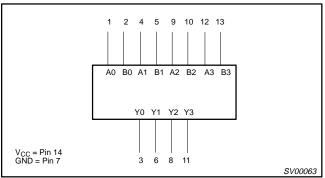
NOTES:

H = High voltage levelL = Low voltage level

LOGIC SYMBOL (IEEE/IEC)



LOGIC SYMBOL



ORDERING INFORMATION

<u> </u>				
PACKAGES	TEMPERATURE RANGE	OUTSIDE NORTH AMERICA	NORTH AMERICA	DWG NUMBER
14-Pin Plastic SO	–40°C to +85°C	74LVT86 D	74LVT86 D	SOT108-1
14-Pin Plastic SSOP	–40°C to +85°C	74LVT86 DB	74LVT86 DB	SOT337-1
14-Pin Plastic TSSOP	-40°C to +85°C	74LVT86 PW	74LVT86PW DH	SOT402-1

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ABSOLUTE MAXIMUM RATINGS1, 2

SYMBOL	PARAMETER	CONDITIONS	RATING	UNIT
V _{CC}	DC supply voltage		-0.5 to +4.6	V
I _{IK}	DC input diode current	V _I < 0	-50	mA
VI	DC input voltage ³		-0.5 to +7.0	V
I _{OK}	DC output diode current	-50	mA	
V _{OUT}	DC output voltage ³	Output in Off or High state	−0.5 to +7.0	V
	DC output ourrent	Output in High state		A
lout	DC output current	Output in Low state	64	mA
T _{stg}	Storage temperature range		-65 to 150	°C

NOTES:

RECOMMENDED OPERATING CONDITIONS

SYMBOL	PARAMETER	LIM	UNIT	
STWIBUL	PARAMETER	MIN	MAX	UNII
V _{CC}	DC supply voltage	2.7	3.6	V
V _I	Input voltage	0	5.5	V
V _{IH}	High-level input voltage	2.0		V
V _{IL}	Low-level Input voltage		0.8	V
I _{OH}	High-level output current		-20	mA
I _{OL}	Low-level output current		32	mA
Δt/Δν	Input transition rise or fall rate; Outputs enabled		10	ns/V
T _{amb}	Operating free-air temperature range	-40	+85	°C

^{1.} Stresses beyond those listed may cause permanent damage to the device. These are stress ratings only and functional operation of the device at these or any other conditions beyond those indicated under "recommended operating conditions" is not implied. Exposure to absolute-maximum-rated conditions for extended periods may affect device reliability.

The performance capability of a high-performance integrated circuit in conjunction with its thermal environment can create junction temperatures which are detrimental to reliability. The maximum junction temperature of this integrated circuit should not exceed 150°C.

3. The input and output negative voltage ratings may be exceeded if the input and output clamp current ratings are observed.

74LVT86

DC ELECTRICAL CHARACTERISTICS

Over recommended operating conditions Voltages are referenced to GND (ground = 0V)

			ı			
SYMBOL	PARAMETER	TEST CONDITIONS	Temp =	+85°C	UNIT	
			MIN	TYP1	MAX	1
V _{IK}	Input clamp voltage	V _{CC} = 2.7V; I _{IK} = -18mA			-1.2	V
		$V_{CC} = 2.7 \text{ to } 3.6 \text{V}; I_{OH} = -100 \mu\text{A}$	V _{CC} -0.2			
V _{OH}	High-level output voltage	V _{CC} = 2.7V; I _{OH} = -6mA	2.4			٧
		V _{CC} = 3.0V; I _{OH} = -20mA	2.0			1
		V _{CC} = 2.7V; I _{OL} = 100μA			0.2	
V _{OL}	Low-level output voltage	V _{CC} = 2.7V; I _{OL} = 24mA			0.5	٧
		V _{CC} = 3.0V; I _{OL} = 32mA			0.5	1
	land lands as summer			10		
Ц	Input leakage current	$V_{CC} = 3.6V$; $V_I = V_{CC}$ or GND			±1	μΑ
I _{OFF}	Output off current	$V_{CC} = 0V$; V_I or $V_O = 0$ to 4.5V			±100	μΑ
I _{CCH}	Outros and a complex account	V_{CC} = 3.6V; Outputs High, V_{I} = GND or V_{CC} , I_{O} = 0			0.02	A
I _{CCL}	Quiescent supply current	V_{CC} = 3.6V; Outputs Low, V_{I} = GND or V_{CC} , I_{O} = 0		1	2	mA
Δl _{CC}	Additional supply current per input pin ²	$V_{\rm CC}$ = 3V to 3.6V; One input at $V_{\rm CC}$ –0.6V, Other inputs at $V_{\rm CC}$ or GND			0.2	μΑ
C _I	Input capacitance	V _I = 3V or 0		3		pF

- All typical values are at V_{CC} = 3.3V and T_{amb} = 25°C.
 This is the increase in supply current for each input at the specified voltage level other than V_{CC} or GND.

AC CHARACTERISTICS

Downloaded from Elcodis.com electronic components distributor

GND = 0V; t_R = t_F = 2.5ns; C_L = 50pF, R_L = 500 Ω ; T_{amb} = -40°C to +85°C.

				LIMITS						
SYMBOL	PARAMETER	WAVEFORM	V _{CC}	\pm = 3.3V \pm 0	V _{CC} = 2.7V	UNIT				
			MIN	TYP ¹	MAX	MAX				
t _{PLH} t _{PHL}	Propagation delay An or Bn to Yn (other input Low)	1	1.0 1.0	3.0 3.5	4.2 5.1	5.3 5.6	ns			
t _{PLH} t _{PHL}	Propagation delay An or Bn to Yn (other input High)	2	1.0 1.0	3.4 3.1	5.2 4.2	6.3 4.4	ns			

^{1.} All typical values are at V_{CC} = 3.3V and T_{amb} = 25°C.

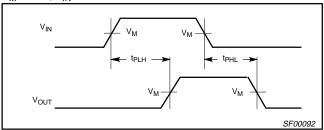
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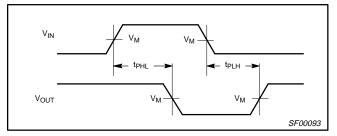
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AC WAVEFORMS

 $V_{M} = 1.5V, V_{IN} = GND \text{ to } 2.7V$

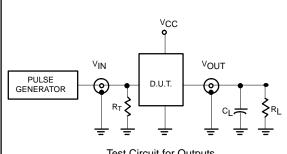


Waveform 1. Propagation Delay for Non-Inverting Outputs

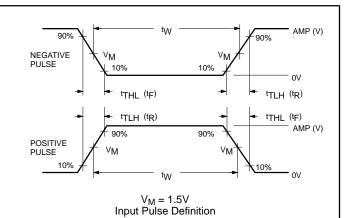


Waveform 2. Propagation Delay for Inverting Outputs

TEST CIRCUIT AND WAVEFORMS



Test Circuit for Outputs



DEFINITIONS

- R_L = Load resistor; see AC CHARACTERISTICS for value.
- C_L = Load capacitance includes jig and probe capacitance; see AC CHARACTERISTICS for value.
- Termination resistance should be equal to $Z_{\mbox{\scriptsize OUT}}$ of $R_T =$ pulse generators.

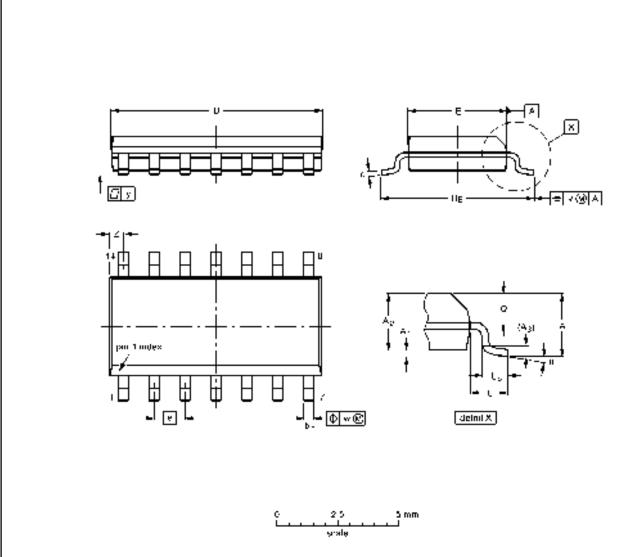
FAMILY	IN	INPUT PULSE REQUIREMENTS											
	Amplitude	Rep. Rate	t _W	t _R	t _F								
74LVT	2.7V	≤10MHz	500ns	≤2.5ns	≤2.5ns								

SV00022

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SO14: plastic small outline package; 14 leads; body width 3.9 mm

SOT108-1



DIMENSIONS (Inch dimensions are derived from the original men dimensions)

LHI IT	A max	4,	Az	43	P	ų	on)	€III	•	ĦE	١	Lp	Ģ	>	4	*	$\mathbf{Z}^{(t)}$	÷
mm	1.75	0. 25 0.10	145 125	0.25	0.45 0.00	0.25 0.19	8.75 0.∞	4.0 3.0	1 27	52 58	116	1.0 U.A	0.7 0.6	0 25	0.25	01	07 00	B°
inches	1.7 0466	00048 00039		0.61	0 0 1 8 0 0 1 4	00049 00075	006 034	0 1t 0 15	0.050	023 023	0.041	0.008	0.028 0.024	001	0.01	0 994	0+69 0012	05

Note

1. Healistor metal profusions of 0.15 mm maximum per side are not included

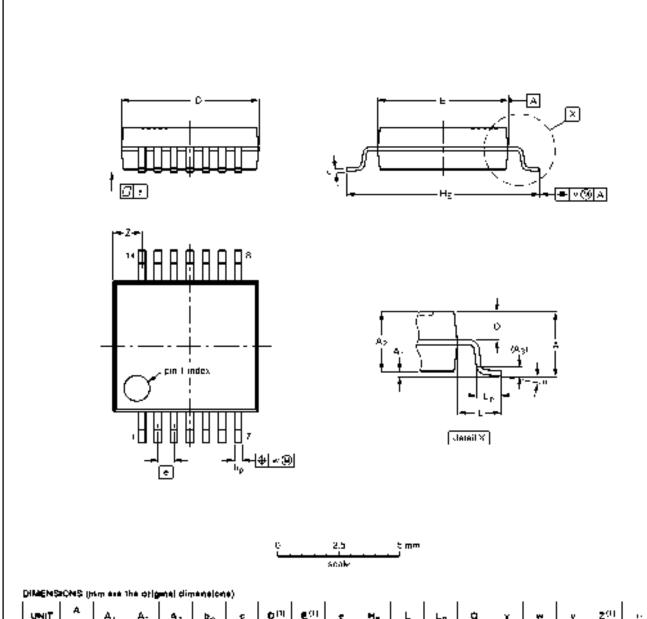
	OUTLINE VERSION		REFER	IENÇES	EUROPEAN	IBBUE DATE	
		IEC	1EDE¢	EITJ	PROJECTION	IBBUE DATE	
	90T108-1	076E06S	M5-012AB		□	91 08 19 95-01-29	

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SSOP14: plastic shrink small outline package; 14 leads; body width 5.3 mm

SOT337-1



UNIT	A mox.	Α,	A:	4,	Þρ	ε	Olul	€01	•	HE	L	Lp	à	٧	~	y	201	1.
mm	20	0.21 0.05	180 165	0.25	0.08 0.25	0.20 0.09	00 64	5.4 5.2	0.65	70 76	125	1.03 0.63	0.9 0.7	0.2	0.10	9.1	14 09	O _D

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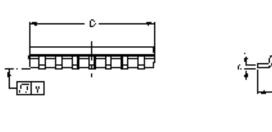
1. Plastic or metal profusions of 0.75 mm maximum perside ery not included

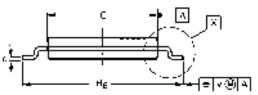
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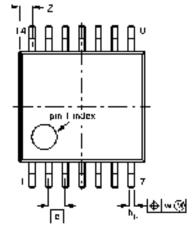
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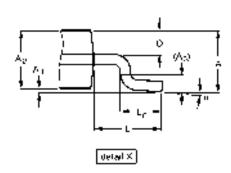
TSSOP14: plastic thin shrink small outline package; 14 leads; body width 4.4 mm

SOT402-1











DIMENSIONS (mm are the original dimensions)

UNIT	A Max	4,	Α,	۵,	b _P	٠	оm	를열	•	H e	L	L _P	a	٧	₩	¥	Z (0)	"
mm	1.10	0.15 0.05	0.03 080	0.25	0.00 0.19	07	5.1 4.9	4.5 4.3	0.65	66 02	1.0	0.75 0.59	04 03	02	0 13	0.1	0.72 0.38	e° o°

Notes

- 1. Plastic or metal profissions of 0.15 mm maximum per side are not included.
- 2. Plastic interload provisions of 0.25 mm maximum per side are not included

OUTLINE		REFER	EUROPEAN	ISSUE DATE			
VERBION	IEC	JEDEC	EITÌ		PROJECTION	ISSUE DATE	
SQT402-1		MO-150			₩	- 94 07 12 95-14-04	

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DEFINITIONS						
Data Sheet Identification	Product Status	Definition				
Objective Specification	Formative or in Design	This data sheet contains the design target or goal specifications for product development. Specifications may change in any manner without notice.				
Preliminary Specification	Preproduction Product	This data sheet contains preliminary data, and supplementary data will be published at a later date. Philips Semiconductors reserves the right to make changes at any time without notice in order to improve design and supply the best possible product.				
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